## NSN 5961-00-900-6377

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.212 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.085 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
0.9 forward voltage, dc
Current Rating Per Characteristic:
1.00 amperes zero-gate-voltage source current any acceptable
Power Rating Per Characteristic:
$250.0 \ milliwatts \ small-signal \ input \ power, \ \ common-collector \ preset$
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Precious Material And Location:
Lead surfaces gold
Precious Material:
Gold
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0